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Fairchild Semiconductor FPAB50PH60

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Distributor of Fairchild Semiconductor: Excellent Integrated System Limited Datasheet of FPAB50PH60 - IC SMART POWER MOD 50A SPM27-HA Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



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vumber	Pin Name	Pin Description		
1	V _{CC}	Common Bias Voltage for IC and IGBTs Driving		
2	COM	Common Supply Ground		
4	IN _(R)	Signal Input for Low-side R-phase IGBT		
5	IN _(S)	Signal Input for Low-side S-phase IGBT		
6	V _{FO}	Fault Output		
7	C _{FOD}	Capacitor for Fault Output Duration Time Selection		
8	C _{SC}	Capacitor (Low-pass Filter) for Over Current Detection		
19	R _(TH)	NTC Thermistor terminal		
20	V _(TH)	NTC Thermistor terminal		
21	V _{AC-}	Negative Terminal of DC–Link (DIODE) for Sensing		
24	N	Negative Rail of DC–Link (IGBT)		
25	R	Output for R Phase		
26	S	Output for S Phase		
27	P _R	Positive Rail of DC–Link		
~18, 22~23	NC	No Connection		
((7) C _{FOD} (CFOD VFO OUT(S) 01 02 04 (25) R		
(5) $IN_{(S)} \ominus IN(S) = IN(S) = IO(1(S)) = $				
((4) $IN_{(R)}$ $IN(R)$ $(24) N$			
((4) IN _(R)	IN(R)		
((4) IN _(R)	UN(R) (23) NC (23) NC		
((3) (3) (4) IN _(R) (4) (2) COM (4)	IN(R) (24) N OUT(R) (23) NC COM (22) NC		
()	(4) IN _(R) (2) COM (IN(R) (24) N OUT(R) (23) NC VCC (21) V _{AC}		

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FPAB50PH60



Absolute Maximum Ratings (T_J = 25°C, Unless Otherwise Specified) **Converter Part**

ltem	Symbol	Condition	Rating	Unit
Supply Voltage	Vi	Applied between R-S	264	V _{RMS}
Supply Voltage (Surge)	V _{i(Surge)}	Applied between R-S	500	V
Output Voltage	V _{PN}	Applied between P- N	450	V
Output Voltage (Surge)	V _{PN(Surge)}	Applied between P- N	500	V
Collector-emitter Voltage	V _{CES}		600	V
Input Current (100% Load)	li	T _C < 95°C, V _i =220V, V _{PN} = 390V, V _{PWM} =20kHz	30	A
Input Current (125% Load)	I _{i(125%)}	T _C < 95°C, V _i =220V, V _{PN} = 390V, V _{PWM} =20kHz, 1min Non-repetitive	37.5	A
Collector Dissipation	P _C	T _C = 25°C per One IGBT	143	W
Operating Junction Temperature	TJ	(Note 1)	-20 ~ 125	°C

Note

1. The maximum junction temperature rating of the power chips integrated within the SPM is 150 °C(@T_C \leq 100°C). However, to insure safe operation of the SPM, the average junction temperature should be limited to T_{J(ave)} \leq 125°C (@T_C \leq 100°C)

Control Part

Item	Symbol	Condition	Rating	Unit
Control Supply Voltage	V _{CC}	Applied between V _{CC} - COM	20	V
Input Signal Voltage	V _{IN}	Applied between IN - COM	-0.3~5.5	V
Fault Output Supply Voltage	V _{FO}	Applied between V _{FO} - COM	-0.3~V _{CC} +0.3	V
Fault Output Current	I _{FO}	Sink Current at V _{FO} Pin	5	mA
Current Sensing Input Voltage	V _{SC}	Applied between C _{SC} - COM	-0.3~V _{CC} +0.3	V

Total System

Item	Symbol	Condition	Rating	Unit
Module Case Operation Temperature	т _с		-20 ~ 100	°C
Storage Temperature	T _{STG}		-40 ~ 125	°C
Isolation Voltage	V _{ISO}	60Hz, Sinusoidal, AC 1 minute, Connection Pins to DBC	2500	V _{rms}

Thermal Resistance

ltem	Symbol	Condition	Min.	Тур.	Max.	Unit
Junction to Case Thermal Resistance	$R_{\theta(j-c)Q}$	IGBT	-	-	0.7	°C/W
	R _{θ(j-c)HD}	High-side diode	-	-	1.5	°C/W
(Referenced to PKG cen- ter)	$R_{\theta(j\text{-}c)LD}$	Low-side diode	-	-	0.85	°C/W

Note : 2. For the measurement point of case temperature(T_C), please refer to Fig. 2.



Electrical Characteristics (T_J = 25°C, Unless Otherwise Specified) **Converter Part**

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
IGBT saturation voltage	V _{CE(sat)}	V _{CC} =15V, V _{IN} = 5V; I _C =50A	-	2.8	3.2	V
High-side diode voltage	V _{FH}	I _C = 50A	-	2.1	2.7	V
Low-side diode voltage	V _{FL}	I _C = 50A	-	1.3	1.7	V
Switching Times	t _{ON}	$V_{PN} = 400V, V_{CC} = 15V, I_C = 30A$ $V_{IN} = 0V \leftrightarrow 5V$, Inductive Load (Note 3)	-	550	-	ns
	t _{C(ON)}		-	200	-	ns
	t _{OFF}		-	430	-	ns
	t _{C(OFF)}		-	180	-	ns
	t _{rr}	7	-	60	-	ns
	l _{rr}	7	-	6	-	Α
Collector - emitter Leakage Current	I _{CES}	$V_{CE} = V_{CES}$	-	-	250	μΑ

Note

t_{ON} and t_{OFF} include the propagation delay time of the internal drive IC. t_{C(ON)} and t_{C(OFF)} are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Fig. 4

Control Part

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Quiescent V _{CC} Supply Cur-	IQCCL	$V_{CC} = 15V, IN = 0V$ $V_{CC} - COM$	-	-	26	mA
rent						
Fault Output Voltage	V _{FOH}	V_{SC} = 0V, V_{FO} Circuit: 4.7k Ω to 5V Pull-up	4.5	-	-	V
	V _{FOL}	V_{SC} = 1V, V_{FO} Circuit: 4.7k Ω to 5V Pull-up	-	-	0.8	V
Over Current Trip Level	V _{OC(ref)}	$V_{CC} = 15V$	0.45	0.5	0.55	V
Supply Circuit Under-	UV _{CCD}	Detection Level	10.7	11.9	13.0	V
Voltage Protection	UV _{CCR}	Reset Level	11.2	12.4	13.2	V
Fault-out Pulse Width	t _{FOD}	C _{FOD} = 33nF (Note 4)	1.4	1.8	2.0	ms
ON Threshold Voltage	V _{IN(ON)}	Applied between IN - COM	3.0	-	-	V
OFF Threshold Voltage	V _{IN(OFF)}		-	-	0.8	V
Resistance of Thermistor	R _{TH}	@ T _C = 25°C (Note Fig. 9)	-	50	-	kΩ
		@ T _C = 80°C (Note Fig. 9)	-	5.76	-	kΩ

Note 4. The fault-out pulse width t_{FOD} depends on the capacitance value of C_{FOD} according to the following approximate equation : $C_{FOD} = 18.3 \times 10^{-6} \times t_{FOD}[F]$











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